TOSHIBA TLP909

TOSHIBA PHOTOREFLECTIVE SENSOR INFRARED LED + PHOTODARLINGTON TRANSISTOR

T L P 9 0 9

PAPER DETECTORS IN COPIERS, FAX MACHINES, PRINTERS, ETC.

DETECTION OF FILM AND COINS

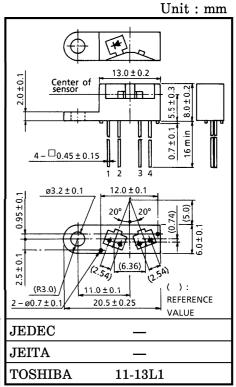
TIMING AND EDGE SENSORS

- Large detection distance: Optimum distance 2.5 mm~4.5 mm
- Side mounting type
- Black mold package impermeable to visible light
- Package material : Polycarbonate

MAXIMUM RATINGS (Ta = 25°C)

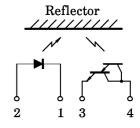
	CHARACTERISTIC	SYMBOL	RATING	UNIT	
LED	Forward Current	$I_{\mathbf{F}}$	50	mA	
	Forward Current Derating (Ta > 25°C)	$\Delta I_{\mathbf{F}} / {^{\circ}\mathbf{C}}$	-0.33	mA/°C	
	Pulse Forward Current (Note 1)	I_{FP}	600	mA	
	Reverse Voltage	v_{R}	5	V	
DETECTOR	Collector-Emitter Voltage	v_{CEO}	30	V	
	Emitter-Collector Voltage	v_{ECO}	5	V	
	Collector Power Dissipation	$P_{\mathbf{C}}$	75	mW	
	Collector Power Dissipation Derating (Ta > 25°C)	△P _C /°C	-1	mW/°C	
	Collector Current	$I_{\mathbf{C}}$	50	mA	
Operating Temperature Range		$T_{ m opr}$	-25~85	°C	
Storage Temperature Range		$\mathrm{T_{stg}}$	-40~100	°C	

(Note 1) : Pulse width $\leq 100 \ \mu s$, Repetitive frequency = $100 \ Hz$



Weight: 0.83 g (typ.)

PIN CONNECTION



- 1. CATHODE
- 2. ANODE
- 3. EMITTER
- 4. COLLECTOR

OPTICAL AND E	LECTRICAL	CHARACTERISTICS	(Ta =	25°C)
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CHARACTERISTIC		SYMBOL	TEST CONDITION	Min	Тур.	Max	UNIT
LED	Forward Voltage	$ m V_{ m F}$	$I_{ m F}=10~{ m mA}$	1.00	1.15	1.30	V
	Reverse Current	$I_{ m R}$	$V_R = 5 V$	_	_	10	μ A
	Peak Emission Wavelength	$\lambda {f P}$	$I_{ m F}=10~{ m mA}$	_	940	_	nm
DETECTOR	Dark Current	I _D (I _{CEO})	$V_{CE} = 16 V, I_{F} = 0$	-	_	0.25	μ A
	Peak Sensitivity Wavelength	$\lambda_{\mathbf{P}}$	_		870	1	nm
COUPLED	Collector Current	$I_{\mathbf{C}}$	$V_{CE} = 2 \text{ V}, I_{F} = 10 \text{ mA}$ (Note 2)	1	_	20	mA
	Leakage Current	I _{LEAK}	$V_{CE} = 5 \text{ V}, I_F = 25 \text{ mA}$ Without Reflector	1		0.25	μ A
	Collector-Emitter Saturation Voltage	V _{CE} (sat)	$ m I_F=10~mA,~I_C=0.5~mA$		0.85	1.2	V
	Rise Time	$t_{\mathbf{r}}$	$V_{CC} = 5 \text{ V}, I_{C} = 10 \text{ mA},$	_	100		.,,
	Fall Time	t_f	$ m R_L = 100~\Omega$	_	100	_	μ s

(Note 2): Reflection ratio 90% at white color paper (KODAK NEUTRAL TEST CARD), Detecting Distance 5mm.

PRECAUTIONS

The following points must be borne in mind.

1. Soldering temperature: 260°C max

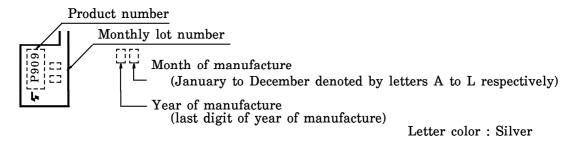
Soldering time: 5 s max

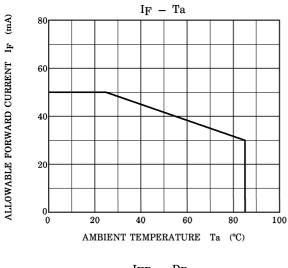
(Soldering must be performed 1.5 mm under the package body.)

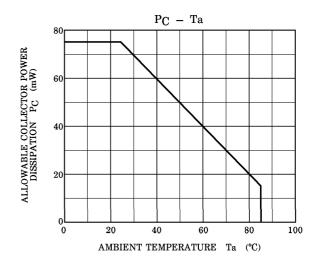
- 2. Clean only the soldered part of the leads. Do not immerse the entire package in the cleaning solvent.
- 3. The package is made of polycarbonate. Oil or chemicals may cause the package to melt or crack.
- 4. Mount the device on a level surface.
- 5. Screws should be tightened to a clamping torque of 0.59 N·m.
- 6. The collector current increases over time due to current flowing in the infrared LED. The design of circuits which incorporate the device must take into account the change in collector current over time. The change in collector current is equal to the reciprocal of the change in LED infrared optical output.

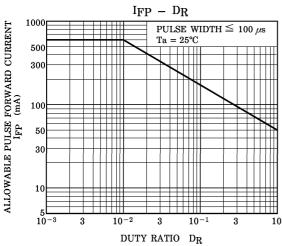
$$\frac{I_{C}(t)}{I_{C}(0)} = \frac{P_{O}(t)}{P_{O}(0)}$$

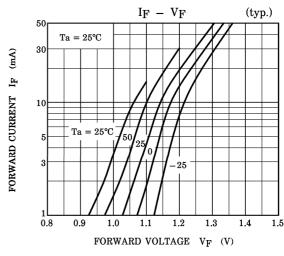
MARKINGS

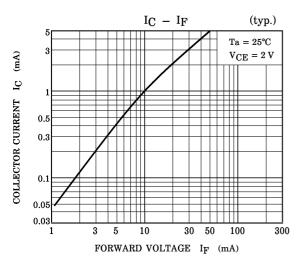


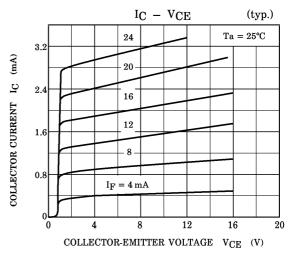


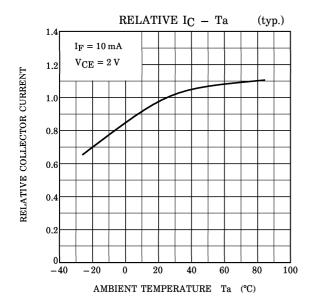


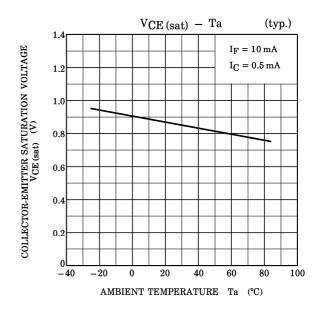


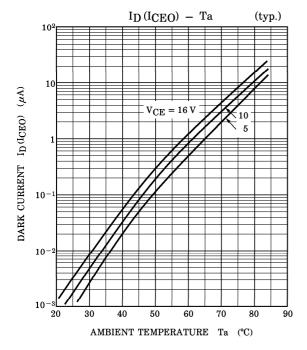


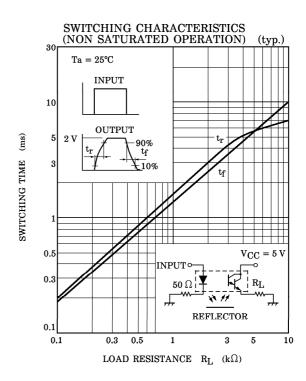


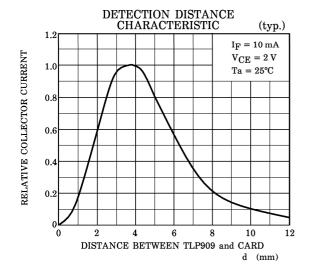


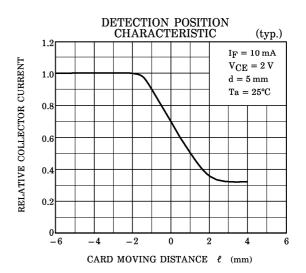


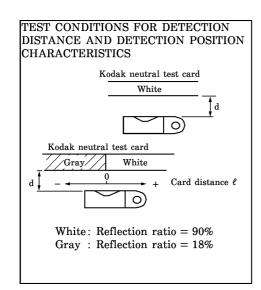












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